

SOD-323 Super Fast Recovery Diode 超快恢复二极管

■Features 特点

Built-in Strain Relief 内应力释放
Fast Switching Speed 快的开关速度
Super Fast Recovery time 超快恢复时间
Surface Mount Device 表面贴装器件
Case 封装:SOD-323



■Maximum Rating 最大额定值

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	ES1JWS	Unit 单位
Device Marking 产品印字		ESH	
Repetitive Peak Reverse Voltage 重复峰值反向电压	V_{RRM}	600	V
DC Reverse Voltage 直流反向电压	V_R	600	V
RMS Reverse Voltage 反向电压均方根值	$V_{R(RMS)}$	420	V
Forward Rectified Current 正向整流电流	I_F	0.5	A
Peak Surge Current 峰值浪涌电流	I_{FSM}	15	A
Thermal Resistance J-A 结到环境热阻	$R_{\theta JA}$	80	$^{\circ}\text{C}/\text{W}$
Junction/Storage Temperature 结温/储藏温度	T_J, T_{stg}	-65to+150	$^{\circ}\text{C}$

■Electrical Characteristics 电特性

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位	Condition 条件
Forward Voltage 正向电压	V_F	1.68	V	$I_F=0.5\text{A}$
Reverse Current 反向电流	I_R	$5(T_A=25^{\circ}\text{C})$ $500(T_A=100^{\circ}\text{C})$	μA	$V_R=V_{RRM}$
Reverse Recovery Time 反向恢复时间	T_{rr}	35	nS	$I_F=0.5\text{A}, I_R=1\text{A}$ $I_{rr}=0.25\text{A}$
Junction Capacitance 结电容	C_J	15	pF	$V_R=4\text{V}, f=1\text{MHz}$

■ Typical Characteristic Curve 典型特性曲线

FIG.1-TYPICAL FORWARD

CHARACTERISTICS

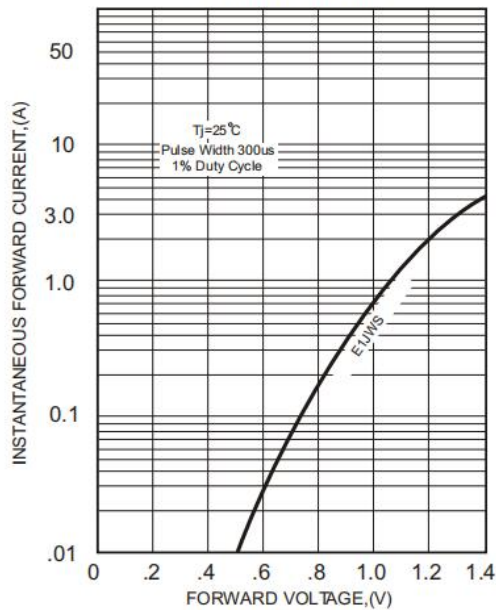


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

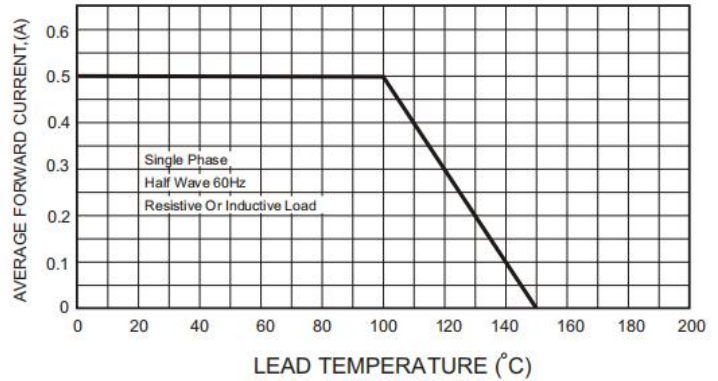
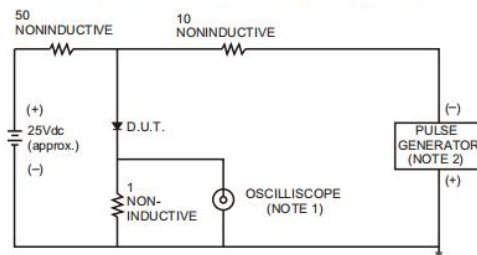


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE

RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

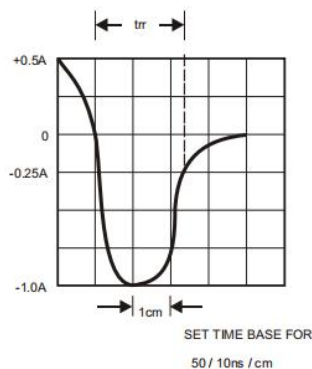


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

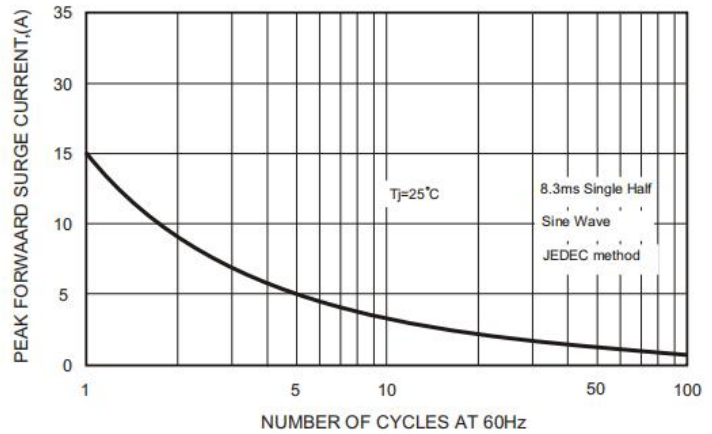
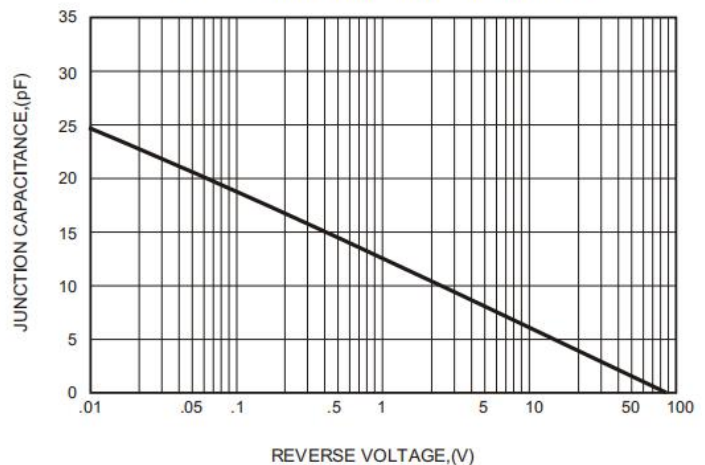
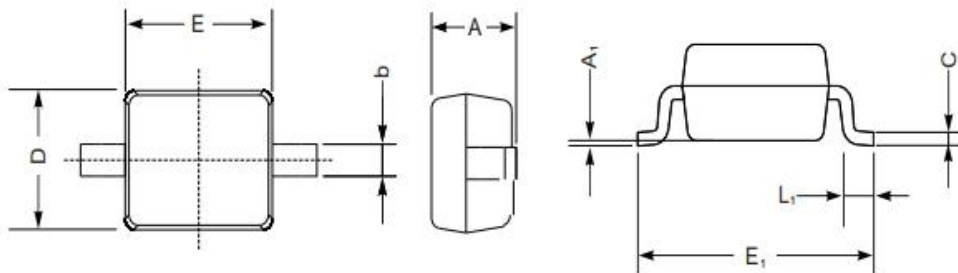


FIG.5-TYPICAL JUNCTION CAPACITANCE



■Dimension 外形封装尺寸



UNIT		A	C	D	E	E ₁	b	L ₁	A ₁
mm	max	1.1	0.15	1.4	1.8	2.75	0.4	0.45	0.2
	min	0.8	0.08	1.2	1.4	2.55	0.25	0.2	—
mil	max	43	5.9	55	70	108	16	16	8
	min	32	3.1	47	63	100	9.8	7.9	—